

PS - 117L · PS - 117D

The PS - 117 photo switches are composed of a modulated infrared emitting diode at the light - emitting side and a modulated photo IC (in which a photodiode, signal processing circuit, constant voltage circuit and modulation circuit are integrated) at the light receiving side.

PS - 117L : High level output at shielding

PS - 117D : Low level output at shielding

FEATURES

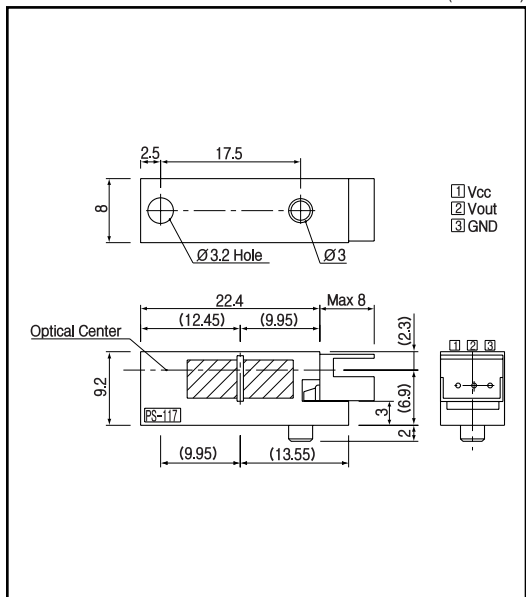
- High - speed response(0.5m sec.)
- Compact and reducing the installation space
- Adjustable of detecting distance
- Possible to keep away from dust because of the detect side is flat
- Resistible to exterior light because of composed of modulate

APPLICATIONS

- Copiers
- Facsimiles

DIMENSIONS

(Unit : mm)



MAXIMUM RATINGS

(Ta=25)

Item	Symbol	Rating	Unit
Supply voltage	V _{CC}	5.5	V
Output voltage *1	V _O	12	V
Low level output current *2	I _{OL}	30	mA
Output transistor power dissipation	P _O	30	mW
Operating temp. *3*4	T _{opr.}	- 10 +60	
Storage temp. *3*4	T _{stg.}	- 20 +70	

*1. Output transistor : VCE *2. Output transistor : IC *3. No icebound or dew

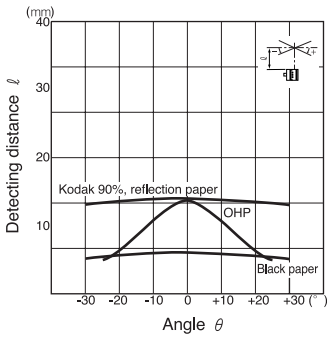
*4. The connector shall be inserted or pulled out at normal temperature.

ELECTRO-OPTICAL CHARACTERISTICS

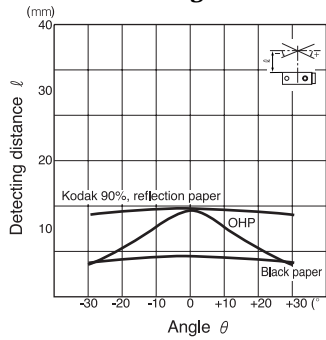
(Ta=25)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Supply voltage	V _{CC}		4.75		5.25	V
Low level output voltage	V _{OL}	V _{CC} =5V, I _{OL} =10mA			0.4	V
High level output voltage	V _{OH}	V _{CC} =5V, R=1k	4.0			V
Supply current	I _{CC}	V _{CC} =5V		16		mA
Minimum detecting distance	L _{DS}	V _{CC} =5V, R=1k			0.5	mm
					1.5	mm
Maximum detecting distance	L _{DL}			6.5		mm
				5.5		mm
Non - detecting distance	L _{NS}			20	mm	
Response speed	t _{PLH} /t _{PHL}	V _{CC} =5V, R=1k			0.5	ms
Exterior light endure	E _V	V _{CC} =5V, R=1k	3,000			lx
Output state			NPN open collector			

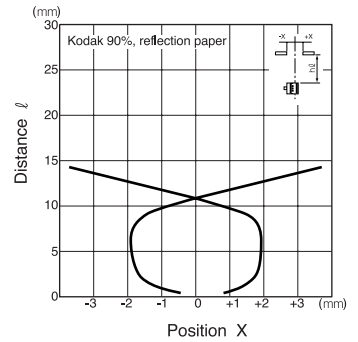
Detecting distance Vs. Angle



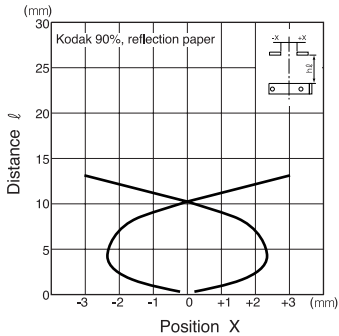
Detecting distance Vs. Angle



Distance Vs. Position



Distance Vs. Position



Relative distance Vs. Ambient temperature

